



2N7002W

N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Low-On Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

- This part is qualified to JEDEC standards (as references in AEC-Q101) for High Reliability.
- <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)

SOT-323 Drain Gate Gate Source TOP VIEW TOP VIEW TOP VIEW

Equivalent Circuit

Ordering Information (Note 4)

	Part Number	Case	Packaging			
2N7002W-7-F		SOT-323	3000/Tape & Reel			
Notes:	1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

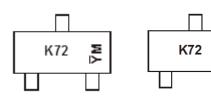
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

M

Marking Information



K72 = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)

 $\overline{Y}M$ = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Chengdu A/T Site

Shanghai A/T Site

Date Code Key

Year	Year 2012		2013		2014	20	15	2016		2017	2	2018
Code Z			А		В	()	D		E		F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteris	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	60	V
Drain-Gate Voltage $R_{GS} \le 1.0M\Omega$	V _{DGR}	60	V	
Gain-Source Voltage	Continuous Pulsed	V _{GSS}	±20 ±40	V
Drain Current (Note 5)	Continuous Continuous @ +100°C Pulsed	Ι _D	115 73 800	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5) Derating above $T_A = +25^{\circ}C$	PD	200 1.60	mW mW
Thermal Resistance, Junction to Ambient	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	۵°

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)							·
Drain-Source Breakdown Voltage		BV _{DSS}	60	70	_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current @ T _C = +125°C	@ T _C = +25°C	I _{DSS}	_	_	1.0 500	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Body Leakage		IGSS	_	_	±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage		V _{GS(th)}	1.0	—	2.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	@ T _J = +25°C	D		1.8	7.5	Ω	V _{GS} = 5.0V, I _D = 0.05A
@ T _j = +125°C		R _{DS(ON)}	_	2.6	13.5	12	V _{GS} = 10V, I _D = 0.5A
On-State Drain Current		I _{D(ON)}	0.5	1.0	_	Α	V _{GS} = 10V, V _{DS} = 7.5V
Forward Transconductance		g fs	80			mS	$V_{DS} = 10V, I_D = 0.2A$
DYNAMIC CHARACTERISTICS (Note 7)							·
Input Capacitance		Ciss	_	22	50	pF	
Output Capacitance		Coss	_	11	25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance		Crss	_	2.0	5.0	pF	1 = 1.0MHZ
SWITCHING CHARACTERISTICS (Note 7	()						·
Turn-On Delay Time		t _{D(ON)}		7.0	20	ns	$V_{DD} = 30V, I_D = 0.2A,$
Turn-Off Delay Time		t _{D(OFF)}		11	20	ns	R _L = 150Ω, V _{GEN} = 10V, R _{GEN} = 25Ω

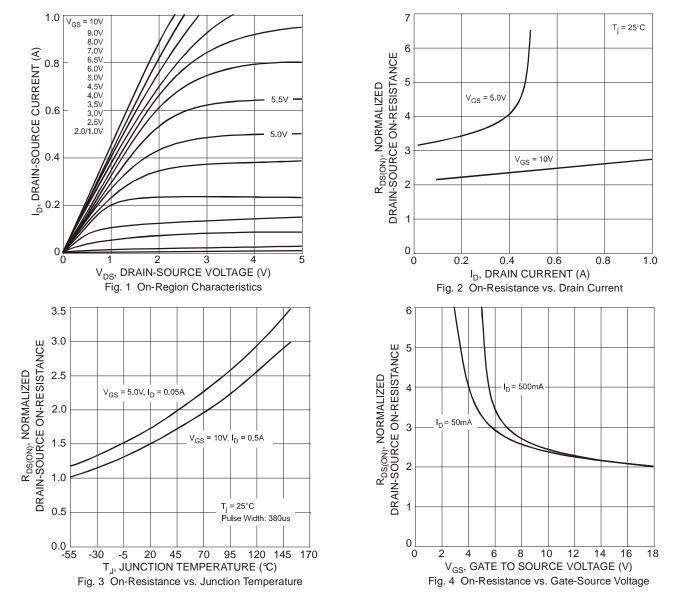
Notes: 5. Device mounted on FR-4 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

6. Short duration pulse test used to minimize self-heating effect.

7. Guaranteed by design. Not subject to production testing.

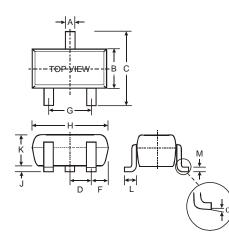


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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



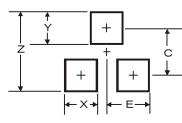
SOT-323						
Dim	Min	Max				
Α	0.25	0.40				
В	1.15	1.35				
С	2.00	2.20				
D	0.65 N	ominal				
F	0.30	0.40				
G	1.20	1.40				
Н	1.80	2.20				
J	0.0	0.10				
K	0.90	1.00				
L	0.25	0.40				
М	0.10	0.18				
α	0°	8°				
All Dimensions in mm						



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Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0

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